

RJH60M0DPQ-A0

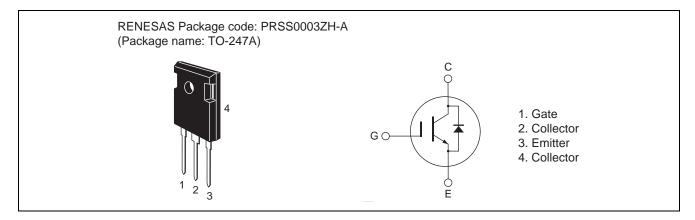
600 V - 22 A - IGBT Application: Inverter

R07DS0535EJ0100 Rev.1.00 Sep 02, 2011

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.8~V$ typ. (at $I_C=22~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 80 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 22 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	45	A
	Tc = 100°C	I _C	22	A
Collector peak current		ic(peak) Note1	90	A
Collector to emitter diode forward current		I _{DF}	22	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	90	A
Collector dissipation		P _C Note2	140	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.89	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	2.3	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

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Electrical Characteristics

 $(Ta = 25^{\circ}C)$

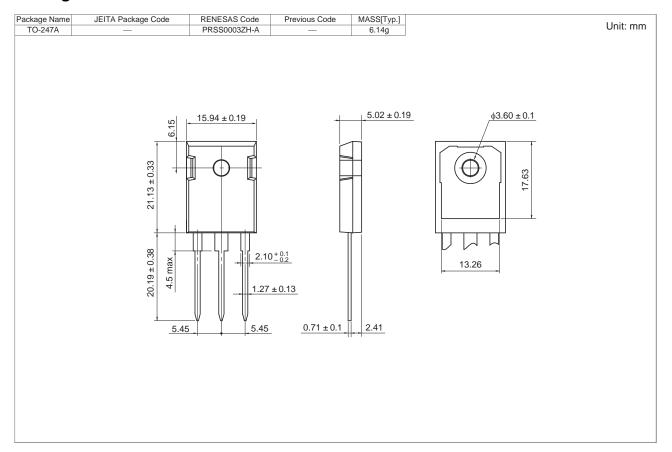
 $di_F/dt = 100 A/\mu s$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	$V_{CE} = 600 \text{ V}, V_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	V _{CE} = 10 V, I _C = 1 mA	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_C = 22 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.2	_	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1050	_	pF	V _{CE} = 25 V V _{GE} = 0 f = 1 MHz	
Output capacitance	Coes	_	70	_	pF		
Reverse transfer capacitance	Cres	_	32	_	pF		
Total gate charge	Qg	_	45	_	nC	V _{GE} = 15 V V _{CE} = 300 V	
Gate to emitter charge	Qge	_	6	_	nC		
Gate to collector charge	Qgc	_	20	_	nC	I _C = 22 A	
Switching time	t _{d(on)}	_	35	_	ns	$V_{CC} = 300 \text{ V}$, $V_{GE} = 15 \text{ V}$	
	t _r	_	20	_	ns	$I_C = 22 \text{ A}$ $Rg = 5 \Omega$ Inductive load	
	t _{d(off)}	_	90	_	ns		
	t _f	_	80	_	ns		
Short circuit withstand time	t _{sc}	6	8	_	μS	Tc = 100 °C	
						$V_{CC} \leq 360~V~,~V_{GE} = 15~V$	
	1	Т	T	1	Т	Note 2	
FRD Forward voltage	V _F	_	1.4	1.9	V	I _F = 22 A ^{Note3}	
FRD reverse recovery time	t _{rr}	_	100	—	ns	$I_F = 22 \text{ A}$	

Notes: 3. Pulse test

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Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJH60M0DPQ-A0-T0	240 pcs	Box (Tube)	

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